Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-924-9029

Inclosure Material:	
Metal	
Overall Length:	
Between 0.240 inches	and 0.260 inches
Terminal Length:	
Between 1.500 inches	and 1.750 inches
Overall Diameter:	
Between 0.335 inches	and 0.370 inches
Internal Configuratio	1:
Junction contact	
Electrode Internally-	lectrically Connected To Case:
Anode	
Mounting Method:	
Terminal	
Terminal Circle Diam	eter:
0.200 inches	
Features Provided:	
Hermetically sealed ca	se
Semiconductor Mate	ial:
Silicon	
Voltage Rating In Vo	ts Per Characteristic:
2.2 forward voltage, p	eak and 1.0 gate trigger voltage, dc and 400.0 reverse voltage, peak
Current Rating Per C	haracteristic:
220.00 milliamperes fo	rward current, total rms megahertz
Maximum Operating	Tempurature Per Measurement Point:
125.0 degrees celsius	ambient air
Special Features:	
Internal junction config	uration arrangement pnpn
Test Data Document:	
81349-mil-s-19500 sp	cification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes com	nercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and per	formance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And C	uantity:
3 uninsulated wire lead	l de la constante de
Specification Data:	
81349-mil-s-19500/27	government specification
Shelf Life:	
N/a	
Unit Of Measure:	
 Demilitarization:	
No	
Fiig:	
A110a0	